

NTLJD2105L

Power MOSFET

8 V, 4.3 A, High Side Load Switch with Level Shift, 2x2 mm WDFN Package

Features

- WDFN 2x2 mm Package with Exposed Drain Pads Offers Excellent Thermal Performance
- Low $R_{DS(on)}$ P-Channel Load Switch with N-channel MOSFET for Level Shift
- N Channel Operated at 1.5 V Gate Drive Voltage Level
- P Channel Operated at 1.5 V Supply Voltage
- Same Footprint as SC88
- Low Profile (<0.8 mm) Allows it to Fit Easily into Extremely Thin Environments
- ESD Protection
- These are Pb-Free Devices

Applications

- High Side Load Switch with Level Shift
- Optimized for Power Management in Ultra Portable Equipment

MOSFET(Q2) MAXIMUM RATINGS

($T_J = 25^\circ\text{C}$ unless otherwise stated)

Parameter			Symbol	Value	Unit
Q2 Input Voltage (V_{DS} , P-Channel)			V_{IN}	8	V
Q1 On/Off Voltage (V_{GS} , N-Channel)			$V_{ON/OFF}$	6	V
Continuous Load Current (Note 1)	Steady State	$T_A = 25^\circ\text{C}$	I_L	4.3	A
		$T_A = 85^\circ\text{C}$		3.1	
Power Dissipation (Note 1)	Steady State	$T_A = 25^\circ\text{C}$	P_D	1.56	W
Continuous Load Current (Note 2)	Steady State	$T_A = 25^\circ\text{C}$	I_L	2.5	A
		$T_A = 85^\circ\text{C}$		1.8	
Power Dissipation (Note 2)		$T_A = 25^\circ\text{C}$	P_D	0.52	W
Pulsed Load Current	$t_p = 10 \mu\text{s}$		I_{LM}	20	A
Operating Junction and Storage Temperature			T_J, T_{STG}	-55 to 150	$^\circ\text{C}$
Source Current (Body Diode) (Note 2)			I_S	-2.7	A
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			T_L	260	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

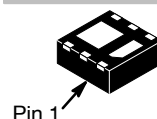
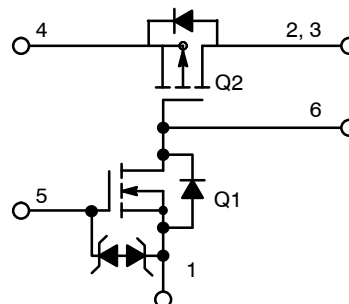
1. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces)
2. Surface-mounted on FR4 board using the minimum recommended pad size.



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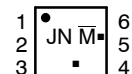
www.onsemi.com

V_{INMAX}	$R_{DS(on)} MAX$	$I_L MAX$
20 V	50 mΩ @ 4.5 V	4.3 A
	60 mΩ @ 2.5 V	
	80 mΩ @ 1.8 V	
	115 mΩ @ 1.5 V	



WDFN6
CASE 506AZ

MARKING DIAGRAM



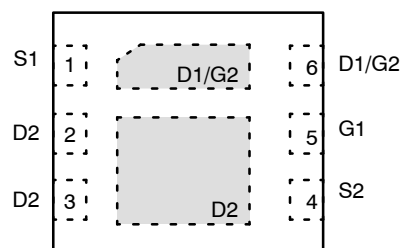
JN = Specific Device Code

M = Date Code

■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient – Steady State (Note 3)	$R_{\theta JA}$	80	$^{\circ}\text{C/W}$
Junction-to-Ambient – $t \leq 5$ s (Note 3)	$R_{\theta JA}$	38	$^{\circ}\text{C/W}$
Junction-to-Ambient – Steady State Min Pad (Note 4)	$R_{\theta JA}$	180	$^{\circ}\text{C/W}$

3. Surface Mounted on FR4 Board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).

4. Surface-mounted on FR4 board using the minimum recommended pad size.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Q2 Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0$ V, $I_D = 250$ μA	-8.0			V
Q2 Forward Leakage Current	I_{FL}	$V_{ON/OFF} = 0$ V, $V_{IN} = 8.0$ V	$T_J = 25^{\circ}\text{C}$		0.1	μA
			$T_J = 85^{\circ}\text{C}$		1	
Q1 Gate-to-Source Leakage Current	I_{GSS}	$V_{DS} = 0$ V, $V_{GS1} = \pm 6$ V			± 100	nA
Q1 Diode Forward On-Voltage	V_{SD}	$I_S = -1.0$ A, $V_{GS1} = 0$ V		-0.8	-1.1	V

ON CHARACTERISTICS

Q1 ON/OFF Voltage	$V_{ON/OFF}$		1.5		8.0	
Q1 Gate Threshold Voltage	$V_{GS1(TH)}$	$V_{GS1} = V_{DS1}$, $I_D = 250$ μA	0.40		1.0	V
Q2 Input Voltage	V_{IN}		1.8		8.0	V
Q2 Drain-to-Source On Resistance	$R_{DS(on)}$	$V_{IN} = 4.5$ V, $I_L = 4.0$ A		33	50	m Ω
		$V_{IN} = 2.5$ V, $I_L = 3.0$ A		40	60	
		$V_{IN} = 1.8$ V, $I_L = 1.7$ A		60	80	
		$V_{IN} = 1.5$ V, $I_L = 1.2$ A		75	115	
Q2 Load Current	I_L	$V_{DROP} \leq 0.2$ V, $V_{IN} = 2.5$ V, $V_{ON/OFF} = 1.5$ V	1.0			A
		$V_{DROP} \leq 0.3$ V, $V_{IN} = 1.8$ V, $V_{ON/OFF} = 1.5$ V	1.0			

TYPICAL PERFORMANCE CURVES ($T_J = 25^\circ\text{C}$ unless otherwise noted)

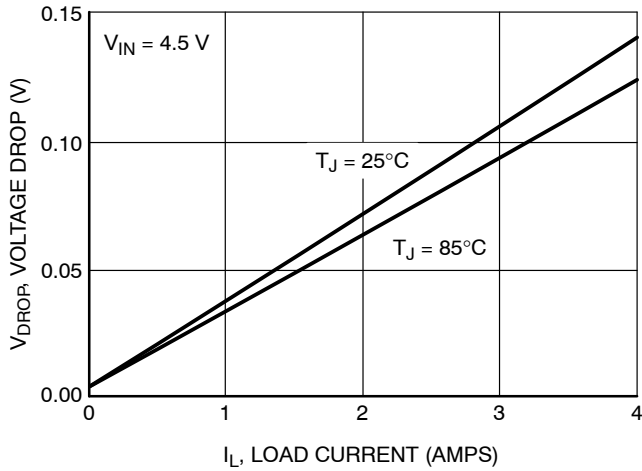


Figure 1. Voltage Drop versus Load Current @ $V_{IN} = 4.5\text{ V}$

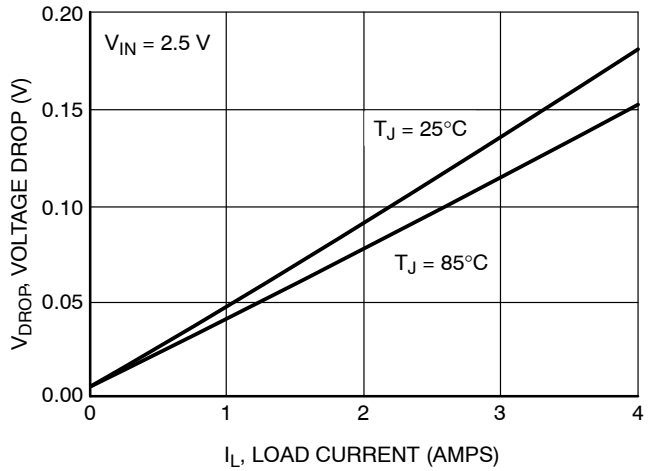


Figure 2. Voltage Drop versus Load Current @ $V_{IN} = 2.5\text{ V}$

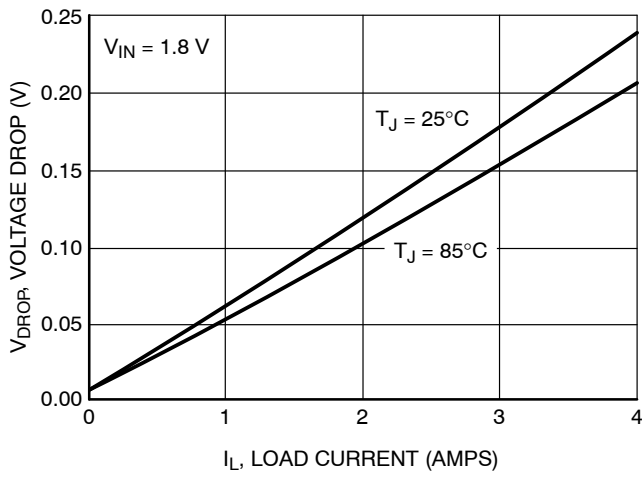


Figure 3. Voltage Drop versus Load Current @ $V_{IN} = 1.8\text{ V}$

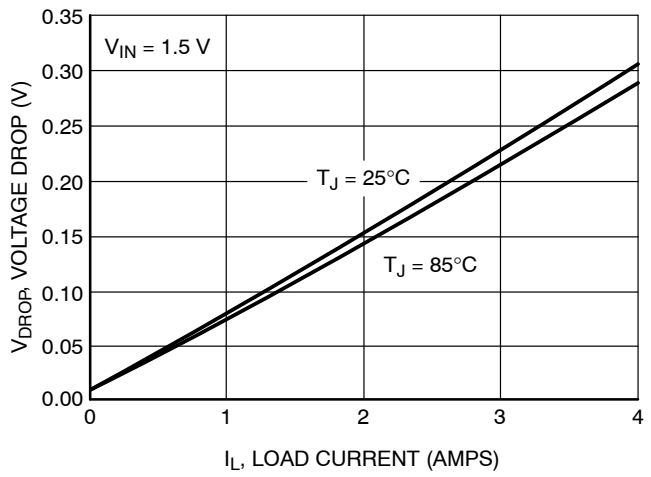


Figure 4. Voltage Drop versus Load Current @ $V_{IN} = 1.5\text{ V}$

TYPICAL PERFORMANCE CURVES ($T_J = 25^\circ\text{C}$ unless otherwise noted)

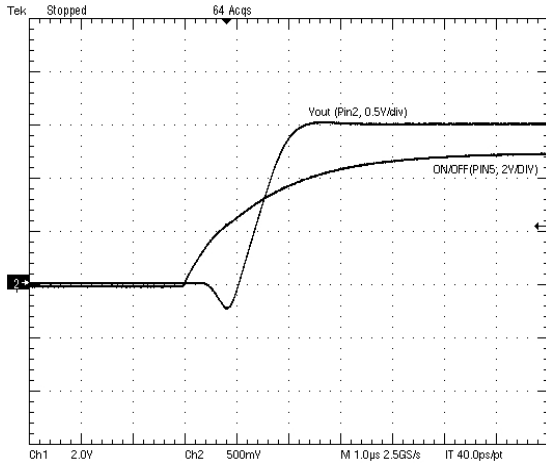


Figure 5. Turn-on
($V_{in} = 1.5\text{ V}$, $R_L = 3\ \Omega$, $R_1 = 1\text{ k}\Omega$, $R_2 = 0$, $C_1 = 47\text{ nF}$)

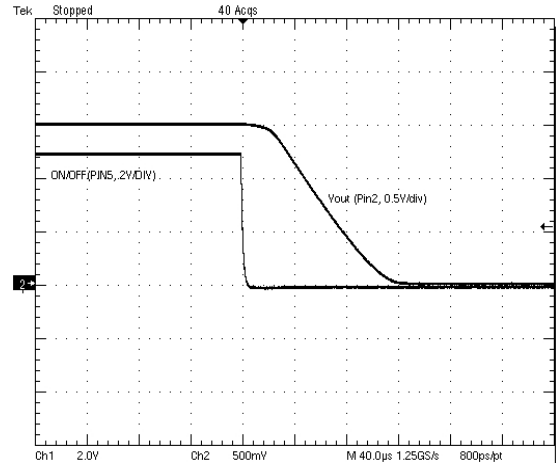


Figure 6. Turn-off
($V_{in} = 1.5\text{ V}$, $R_L = 3\ \Omega$, $R_1 = 1\text{ k}\Omega$, $R_2 = 0$, $C_1 = 47\text{ nF}$)

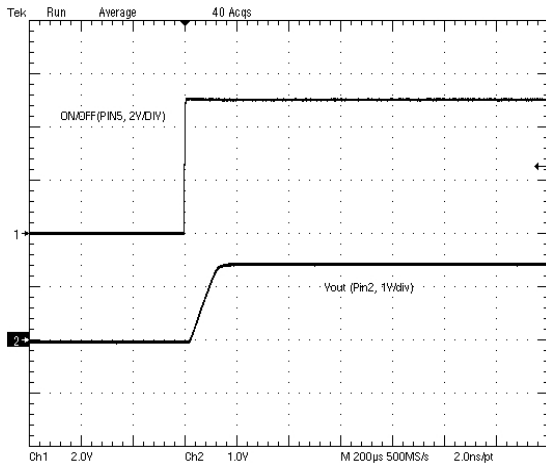


Figure 7. Turn-on
($V_{in} = 1.5\text{ V}$, $R_L = 3\ \Omega$, $R_1 = 10\text{ k}\Omega$, $R_2 = 1\text{ k}\Omega$, $C_1 = 47\text{ nF}$)

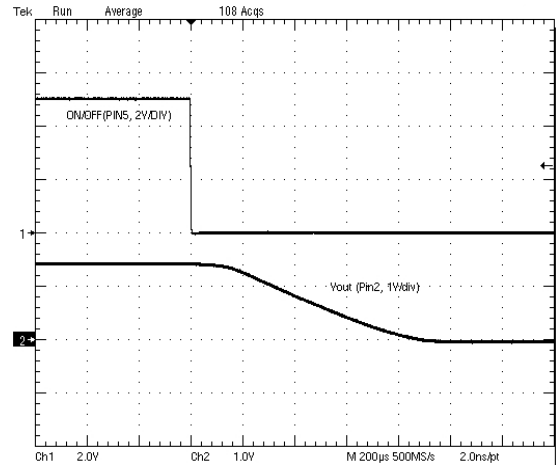


Figure 8. Turn-off
($V_{in} = 1.5\text{ V}$, $R_L = 3\ \Omega$, $R_1 = 10\text{ k}\Omega$, $R_2 = 1\text{ k}\Omega$, $C_1 = 47\text{ nF}$)

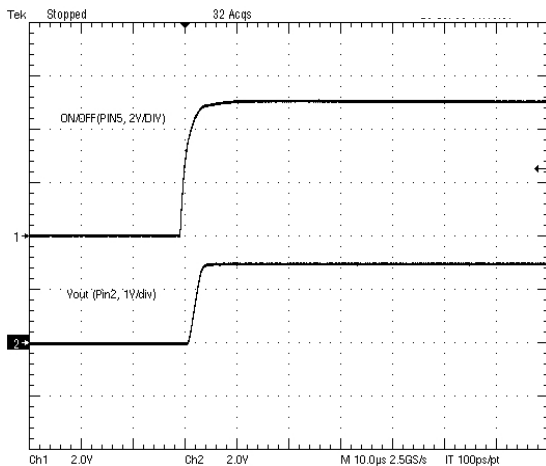


Figure 9. Turn-on
($V_{in} = 3\text{ V}$, $R_L = 3\ \Omega$, $R_1 = 10\text{ k}\Omega$, $R_2 = 1\text{ k}\Omega$, $C_1 = 47\text{ nF}$)

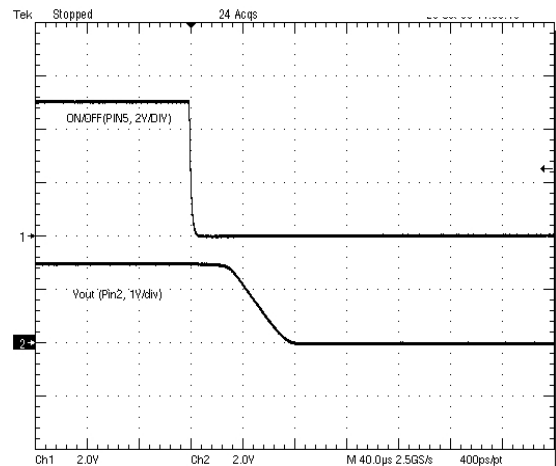


Figure 10. Turn-off
($V_{in} = 3\text{ V}$, $R_L = 3\ \Omega$, $R_1 = 10\text{ k}\Omega$, $R_2 = 1\text{ k}\Omega$, $C_1 = 47\text{ nF}$)

NTLJD2105L

TYPICAL PERFORMANCE CURVES ($T_J = 25^\circ\text{C}$ unless otherwise noted)

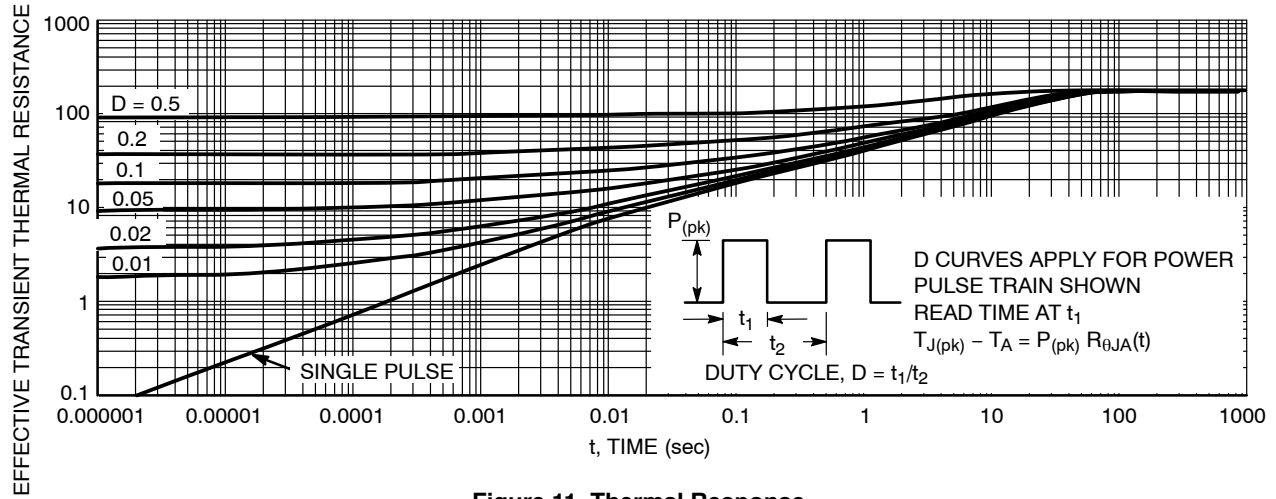


Figure 11. Thermal Response

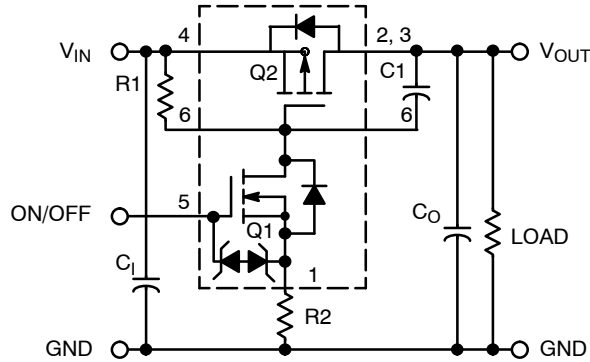


Figure 12. Load Switch Application

Components	Description	Value
R1	Pull-up Resistor	Typical 10 k Ω to 1.0 M Ω *
R2	Optional Slew-Rate Control	Typical 0 k Ω to 100 k Ω *
C _O , C _I	Output Capacitance	Usually < 1.0 μF
C1	Optional In-Rush Current Control	Typical ≤ 1000 pF

*Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on.

ORDERING INFORMATION

Device	Package	Shipping [†]
NTLJD2105LTBG	WDFN6 (Pb-Free)	3000 / Tape & Reel

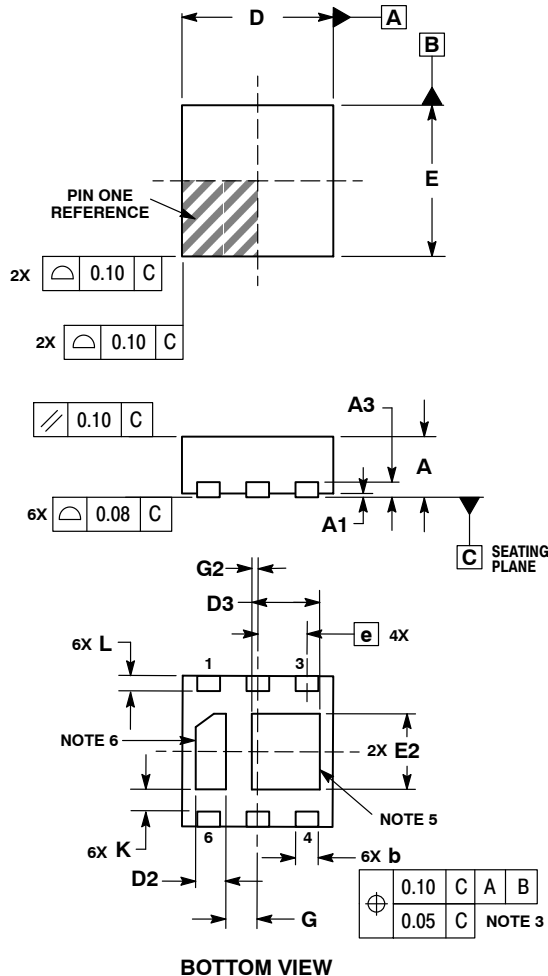
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



SCALE 4:1

WDFN6, 2x2 CASE 506AZ-01 ISSUE A

DATE 25 APR 2006



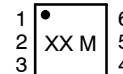
STYLE 1:
PIN 1. SOURCE 1
2. DRAIN 2
3. DRAIN 2
4. SOURCE 2
5. GATE 1
6. DRAIN 1

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20mm FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
1. PINS 2 & 3 CONNECTED TO LARGE FLAG.
2. PIN 6 CONNECTED TO SMALL FLAG.

DIM	MILLIMETERS	
	MIN	MAX
A	0.70	0.80
A1	0.00	0.05
A3	0.20 REF	
b	0.25	0.35
D	2.00 BSC	
D2	0.30	0.50
D3	0.80	1.00
E	2.00 BSC	
E2	0.90	1.10
e	0.65 BSC	
G	0.41 REF	
G2	0.085 REF	
K	0.25 REF	
L	0.20	0.30

GENERIC MARKING DIAGRAM*

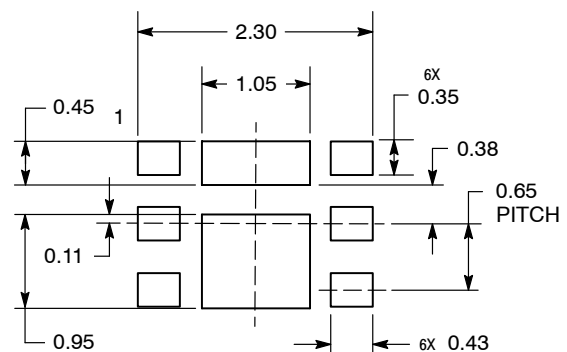


XX = Specific Device Code

M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

SOLDERMASK DEFINED MOUNTING FOOTPRINT



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	6 PIN WDFN 2X2, 0.65P	PAGE 1 OF 1

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